

Features

- 10 kV – ESD Protection
- Two Comparators with Common Reference
- Tight Threshold Tolerance
- Constant Threshold
- NPN Output
- Interference and Damage-protection According to VDE 0839 and ISO/CD 7637 EMI Protection
- Reversal Polarity Protection
- Load-dump Protection



Current Monitor IC

U4793B

1. Description

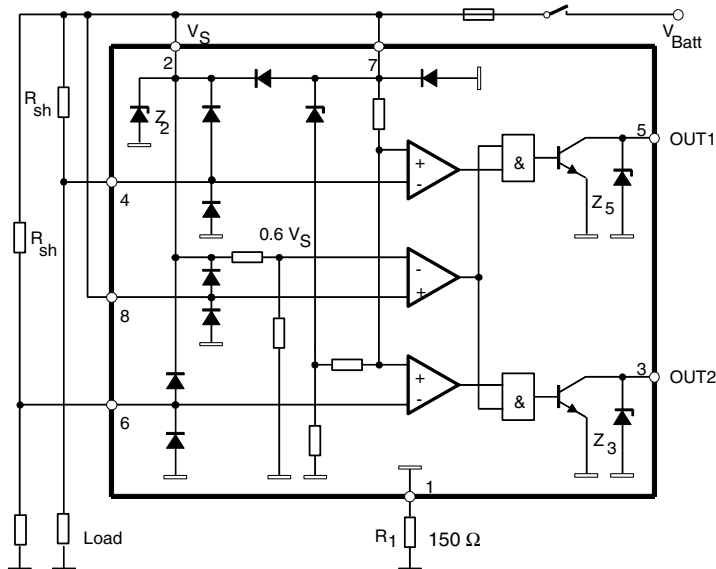
The bipolar U4793B is designed to monitor overload or a short circuit in automotive or industrial applications. The threshold is tied to $V_{4,6} = V_S - V_T$ where $V_T = 44.5$ mV. It is independent of the supply voltage, V_S . If the voltage drop across shunt resistor, R_{sh} , exceeds this value, the output is turned on, otherwise the output is turned off.

Without supply voltage or open input pin 8, the output is turned off. The output break-down voltage is determined by the Z-diodes Z_3 and Z_5 with a typical value of $V_Z = 22$ V.

An unused comparator input must be connected to pin 7.

2. Block Diagram

Figure 2-1. Schematic and Application Circuit



3. Pin Configuration

Figure 3-1. Pinning DIP8/SO8

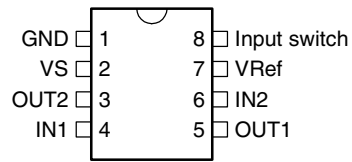


Table 3-1. Pin Description

Pin	Symbol	Function
1	GND	Reference point, ground
2	VS	Supply voltage
3	OUT2	Output 2
4	IN1	Input 1
5	OUT1	Output 1
6	IN2	Input 2
7	VRef	Reference voltage
8	Input switch	Input switch

4. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Symbol	Value	Unit
Supply voltage; pins 2 and 7	V_S	16.5	V
Current consumption $t = 2$ ms, measured at pin 1 (GND), pin 1	I_1	1.5	A
Output current, pins 3 and 5	$I_{3,5}$	20	mA
Input voltage reference point pin 7, pins 4 and 6	$-V_{4,6}$	6	V
Power dissipation, $T_{amb} = 125^\circ\text{C}$ DIP8 SO8	P_{tot}	220 150	mW mW
$T_{amb} = 95^\circ\text{C}$ DIP8 SO8	P_{tot}	420 360	mW mW
$T_{amb} = 60^\circ\text{C}$ DIP8 SO8	P_{tot}	690 560	mW mW
Ambient temperature range	T_{amb}	-40 to +125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to +125	$^\circ\text{C}$
Junction temperature	T_j	150	$^\circ\text{C}$

5. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient DIP8 SO8	R_{thJA} R_{thJA}	110 160	K/W K/W

6. Electrical Characteristics

$V_S = 9\text{V to }15\text{V}$, $T_{amb} = -40^\circ\text{C to }+125^\circ\text{C}$, unless otherwise specified (see [Figure 2-1 on page 1](#))

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
1	Supply								
1.1	Supply voltage		2, 7	V_S	9		15	V	A
1.2	Internal Z-diode Z_2		2	V_Z	20			V	A
1.3	Current consumption	$V_S = 12\text{V}$ measured $T_{amb} = -40^\circ\text{C}$	1	I_1	3.5	4.8	6.0	mA	C
1.4		$V_S = 12\text{V}$ measured $T_{amb} = 25^\circ\text{C}$	1	I_1	2.8	3.4	6.0	mA	A
1.5		$V_S = 12\text{V}$ measured $T_{amb} = 125^\circ\text{C}$	1	I_1	2.0	2.6	3.2	mA	C

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

6. Electrical Characteristics (Continued)

$V_S = 9V$ to $15V$, $T_{amb} = -40^\circ C$ to $+125^\circ C$, unless otherwise specified (see [Figure 2-1 on page 1](#))

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
2	Output								
2.1	Output saturation voltage	$V_S = 9V$, $I_{3,5} = 10\text{ mA}$ $T_{amb} = 25^\circ C$	3, 5	V_{sat}			0.5	V	A
2.2	Output Z-diodes Z_3, Z_5		3, 5	V_Z	21			V	A
3	Control Signal								
3.1	Control signal threshold	$I_{3,5} = 1\text{ mA}$, Figure 6-1 $T_{amb} = -40^\circ C$	4, 6	$-V_T$	42	44	46	mV	C
3.2		$I_{3,5} = 1\text{ mA}$, Figure 6-1 $T_{amb} = 25^\circ C$	4, 6	$-V_T$	43	44.5	46	mV	A
3.3		$I_{3,5} = 1\text{ mA}$, Figure 6-1 $T_{amb} = 125^\circ C$	4, 6	$-V_T$	44.5	46	47.5	mV	C
3.4	Temperature coefficient of control signal threshold			TC		15		$\mu V/K$	C
3.5	Input currents	$T_{amb} = -40^\circ C$	4, 6	I_I	100		190	nA	C
3.6	Pins connected to 12V	$T_{amb} = 25^\circ C$		I_I	60	100	150	nA	A
3.7		$T_{amb} = 125^\circ C$		I_I	30		110	nA	C
3.8	Input currents	$T_{amb} = -40^\circ C$	8	I_I	5.5		7.0	μA	C
3.9	Pins connected to 12V	$T_{amb} = 25^\circ C$		I_I	4.0	5.0	5.5	μA	A
3.10		$T_{amb} = 125^\circ C$		I_I	3.0		4.5	μA	C
4	Threshold								
4.1	Threshold voltage	Switch identification $T_{amb} = -40^\circ C$	8	V_8	$0.47 \times V_S$		$0.69 \times V_S$	V	C
4.2		Switch identification $T_{amb} = 25^\circ C$		V_8	$0.47 \times V_S$	$0.6 V_S$	$0.69 \times V_S$	V	A
4.3		Switch identification $T_{amb} = 125^\circ C$		V_8	$0.47 \times V_S$		$0.69 \times V_S$	V	C
5	Switch Delay ($R_L = 10\text{ k}\Omega$ connected from Pin 3 or Pin 5 to V_{Batt})								
5.1	Delay time	$T_{amb} = -40^\circ C$	3, 5	$t_{d(on)}$	3	4	6	μs	C
5.2	Switch-on	$T_{amb} = 25^\circ C$		$t_{d(on)}$	4	6	8	μs	C
5.3	High to low	$T_{amb} = 125^\circ C$		$t_{d(on)}$	5	7	9	μs	C
5.4	Delay time	$T_{amb} = -40^\circ C$		$t_{d(off)}$	16	24	32	μs	C
5.5	Switch-off	$T_{amb} = 25^\circ C$		$t_{d(off)}$	18	30	50	μs	A
5.6	Low to high	$T_{amb} = 125^\circ C$		$t_{d(off)}$	30	50	70	μs	C

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Figure 6-1. Timing Diagram

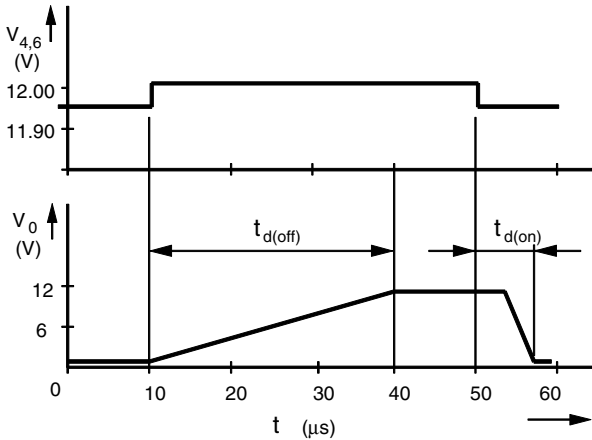
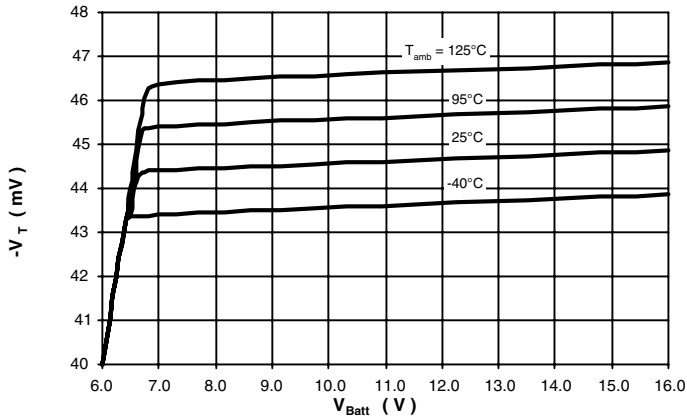


Figure 6-2. Threshold Voltage = f (V_{Batt} and Temperature)



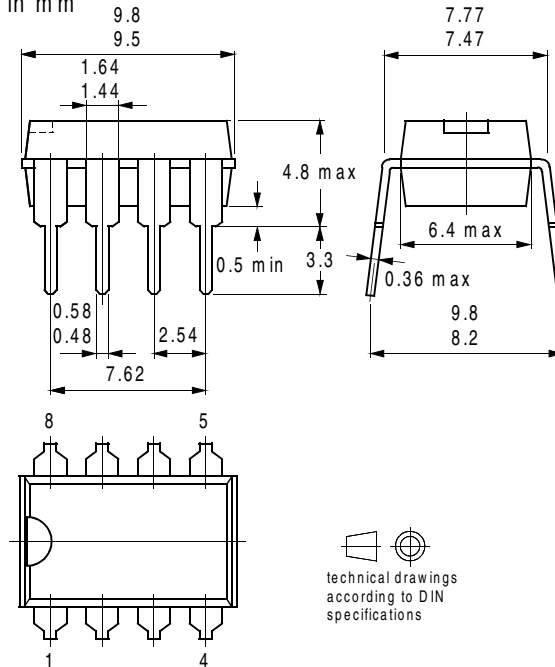
7. Ordering Information

Extended Type Number	Package	Remarks
U4793B-MY	DIP8	Tube, Pb-free
U4793B-MFPY	SO8	Tube, Pb-free
U4793B-MFPG3Y	SO8	Taped and reeled, Pb-free

8. Package Information

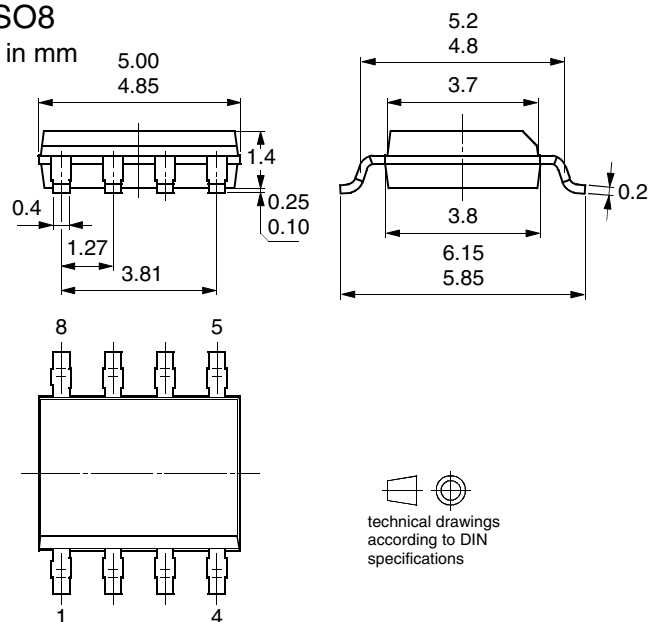
Package DIP8

Dimensions in mm



Package SO8

Dimensions in mm



9. Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Revision No.	History
4557B-AUTO-09/05	<ul style="list-style-type: none">• Put datasheet in a new template• Pb-free logo on page 1 added• Ordering Information on page 6 changed



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